

MPS2222, MPS2222A

MPS2222A is a Preferred Device

General Purpose Transistors

NPN Silicon



ON Semiconductor®

<http://onsemi.com>

Features

- Pb-Free Packages are Available*

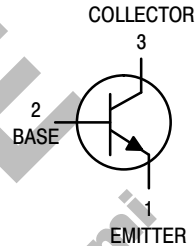
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage MPS2222 MPS2222A	V_{CEO}	30 40	Vdc
Collector - Base Voltage MPS2222 MPS2222A	V_{CBO}	60 75	Vdc
Emitter - Base Voltage MPS2222 MPS2222A	V_{EBO}	5.0 6.0	Vdc
Collector Current - Continuous	I_C	600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

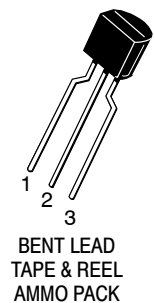
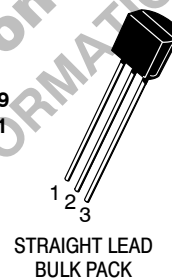
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

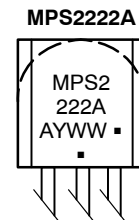
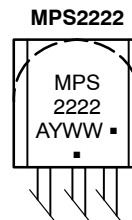
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



TO-92
CASE 29
STYLE 1



MARKING DIAGRAMS



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPS2222, MPS2222A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = 10 mA _{dc} , I _B = 0)	MPS2222 MPS2222A	V _{(BR)CEO}	30 40	– –	V _{dc}
Collector – Base Breakdown Voltage (I _C = 10 μA _{dc} , I _E = 0)	MPS2222 MPS2222A	V _{(BR)CBO}	60 75	– –	V _{dc}
Emitter – Base Breakdown Voltage (I _E = 10 μA _{dc} , I _C = 0)	MPS2222 MPS2222A	V _{(BR)EBO}	5.0 6.0	– –	V _{dc}
Collector Cutoff Current (V _{CE} = 60 V _{dc} , V _{EB(off)} = 3.0 V _{dc})	MPS2222A	I _{CEX}	–	10	nA _{dc}
Collector Cutoff Current (V _{CB} = 50 V _{dc} , I _E = 0) (V _{CB} = 60 V _{dc} , I _E = 0) (V _{CB} = 50 V _{dc} , I _E = 0, T _A = 125°C) (V _{CB} = 50 V _{dc} , I _E = 0, T _A = 125°C)	MPS2222 MPS2222A MPS2222 MPS2222A	I _{CBO}	– – – –	0.01 0.01 10 10	μA _{dc}
Emitter Cutoff Current (V _{EB} = 3.0 V _{dc} , I _C = 0)	MPS2222A	I _{EBO}	–	100	nA _{dc}
Base Cutoff Current (V _{CE} = 60 V _{dc} , V _{EB(off)} = 3.0 V _{dc})	MPS2222A	I _{BL}	–	20	nA _{dc}
ON CHARACTERISTICS					
DC Current Gain (I _C = 0.1 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , T _A = –55°C) (I _C = 150 mA _{dc} , V _{CE} = 10 V _{dc}) (Note 1) (I _C = 150 mA _{dc} , V _{CE} = 1.0 V _{dc}) (Note 1) (I _C = 500 mA _{dc} , V _{CE} = 10 V _{dc}) (Note 1)	MPS2222A only MPS2222 MPS2222A	h _{FE}	35 50 75 35 100 50 30 40	– – – – 300 – – –	–
Collector – Emitter Saturation Voltage (Note 1) (I _C = 150 mA _{dc} , I _B = 15 mA _{dc}) (I _C = 500 mA _{dc} , I _B = 50 mA _{dc})	MPS2222 MPS2222A MPS2222 MPS2222A	V _{CE(sat)}	– – – –	0.4 0.3 1.6 1.0	V _{dc}
Base – Emitter Saturation Voltage (Note 1) (I _C = 150 mA _{dc} , I _B = 15 mA _{dc}) (I _C = 500 mA _{dc} , I _B = 50 mA _{dc})	MPS2222 MPS2222A MPS2222 MPS2222A	V _{BE(sat)}	– 0.6 – –	1.3 1.2 2.6 2.0	V _{dc}
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (Note 2) (I _C = 20 mA _{dc} , V _{CE} = 20 V _{dc} , f = 100 MHz)	MPS2222 MPS2222A	f _T	250 300	– –	MHz
Output Capacitance (V _{CB} = 10 V _{dc} , I _E = 0, f = 1.0 MHz)		C _{obo}	–	8.0	pF
Input Capacitance (V _{EB} = 0.5 V _{dc} , I _C = 0, f = 1.0 MHz)	MPS2222 MPS2222A	C _{ibo}	– –	30 25	pF
Input Impedance (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz)	MPS2222A MPS2222A	h _{ie}	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz)	MPS2222A MPS2222A	h _{re}	– –	8.0 4.0	X 10 ^{–4}
Small-Signal Current Gain (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz)	MPS2222A MPS2222A	h _{fe}	50 75	300 375	–
Output Admittance (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz)	MPS2222A MPS2222A	h _{oe}	5.0 25	35 200	μmhos
Collector Base Time Constant (I _E = 20 mA _{dc} , V _{CB} = 20 V _{dc} , f = 31.8 MHz)	MPS2222A	rb'C _c	–	150	ps
Noise Figure (I _C = 100 μA _{dc} , V _{CE} = 10 V _{dc} , R _S = 1.0 kΩ, f = 1.0 kHz)	MPS2222A	NF	–	4.0	dB

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. f_T is defined as the frequency at which |h_{fe}| extrapolates to unity.

MPS2222, MPS2222A

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
SWITCHING CHARACTERISTICS MPS2222A only				
Delay Time	t_d	-	10	ns
Rise Time	t_r	-	25	ns
Storage Time	t_s	-	225	ns
Fall Time	t_f	-	60	ns

SWITCHING TIME EQUIVALENT TEST CIRCUITS

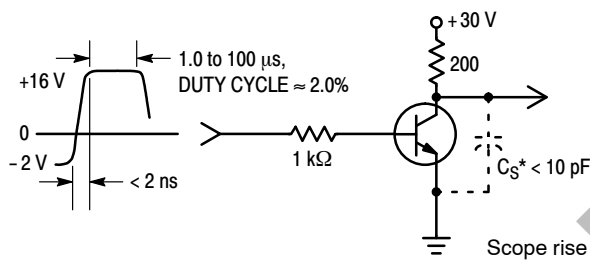


Figure 1. Turn-On Time

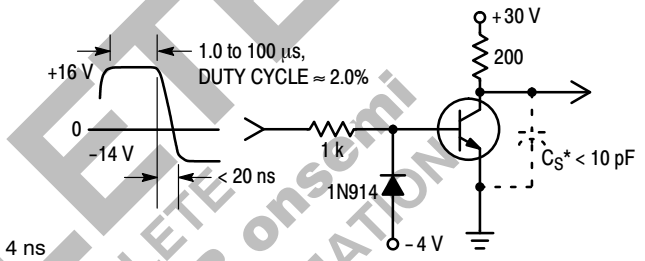


Figure 2. Turn-Off Time

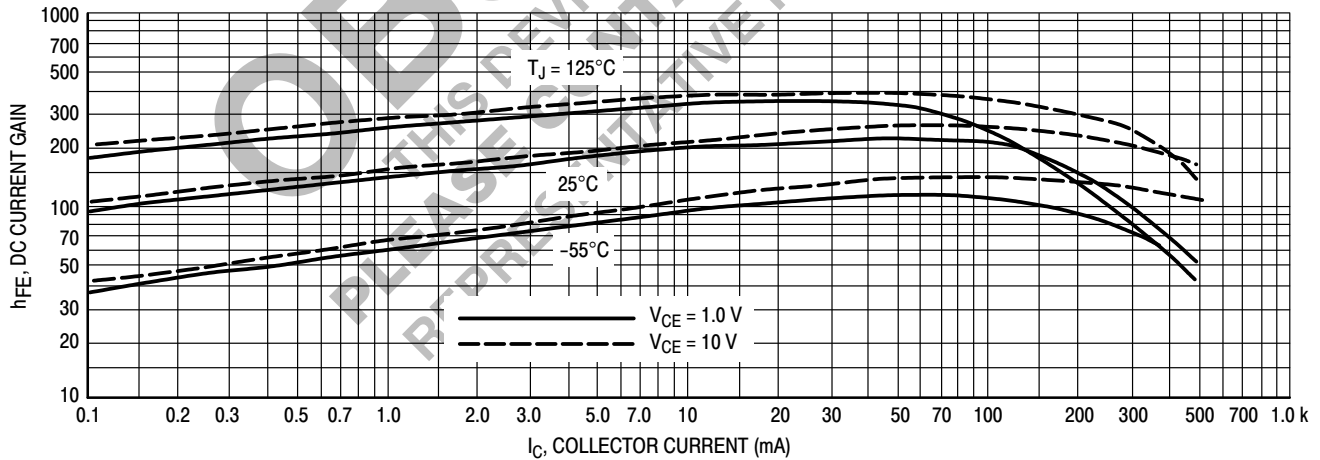


Figure 3. DC Current Gain

MPS2222, MPS2222A

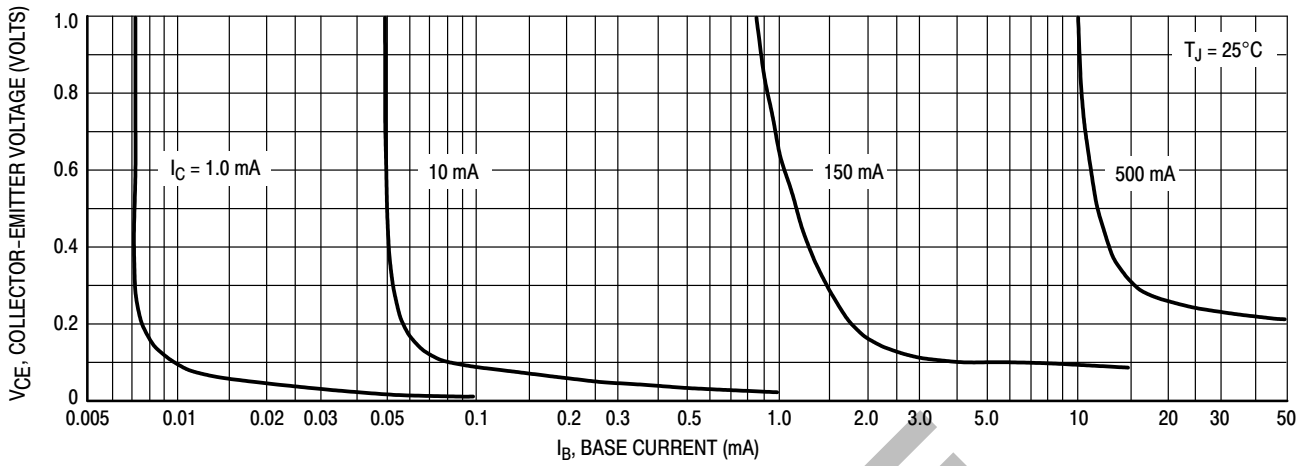


Figure 4. Collector Saturation Region

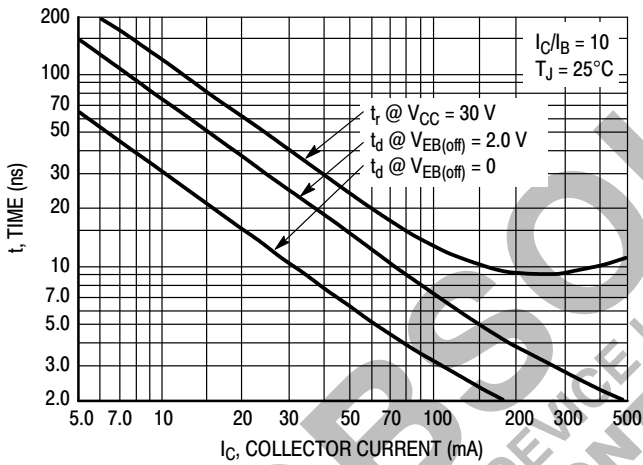


Figure 5. Turn-On Time

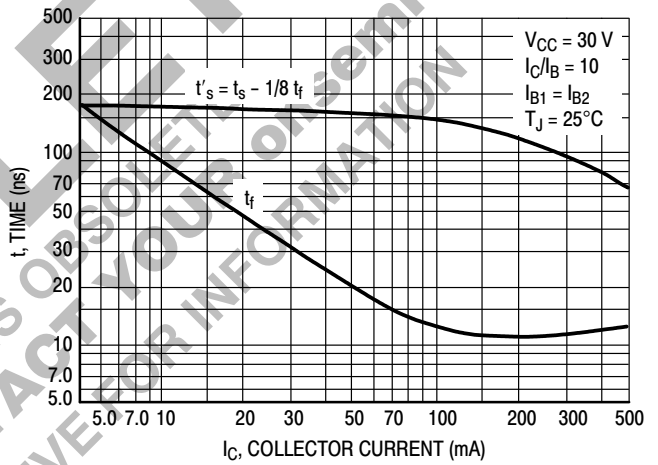


Figure 6. Turn-Off Time

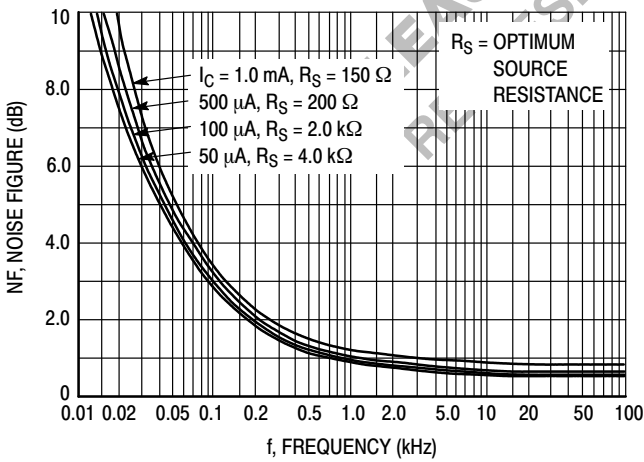


Figure 7. Frequency Effects

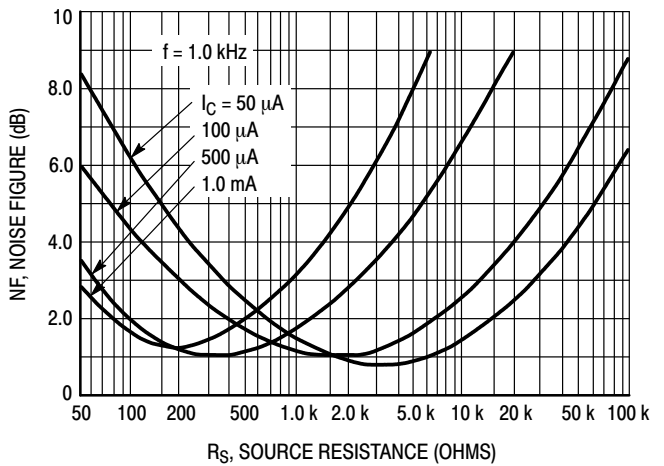


Figure 8. Source Resistance Effects

MPS2222, MPS2222A

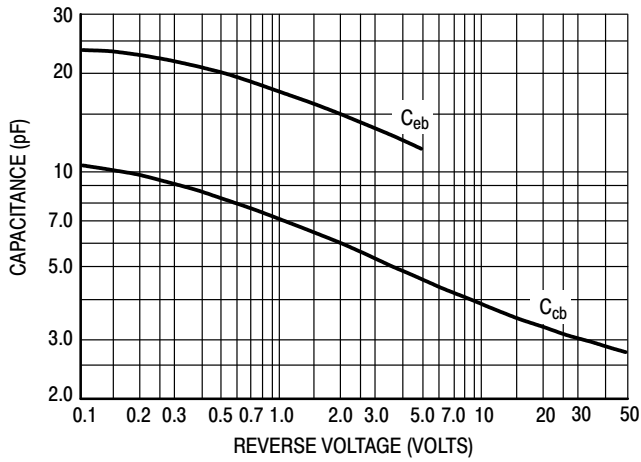


Figure 9. Capacitances

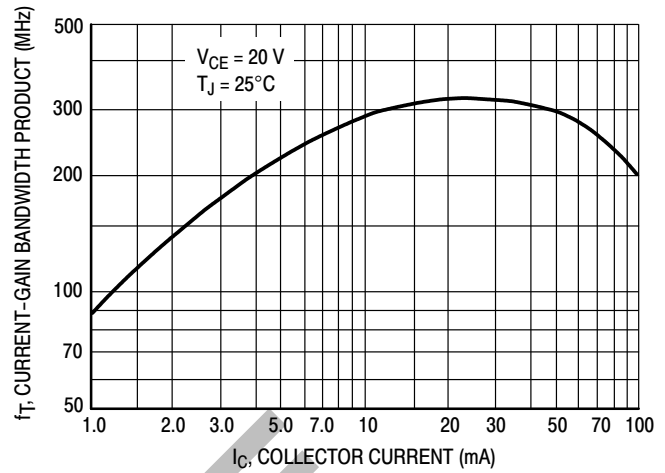


Figure 10. Current-Gain Bandwidth Product

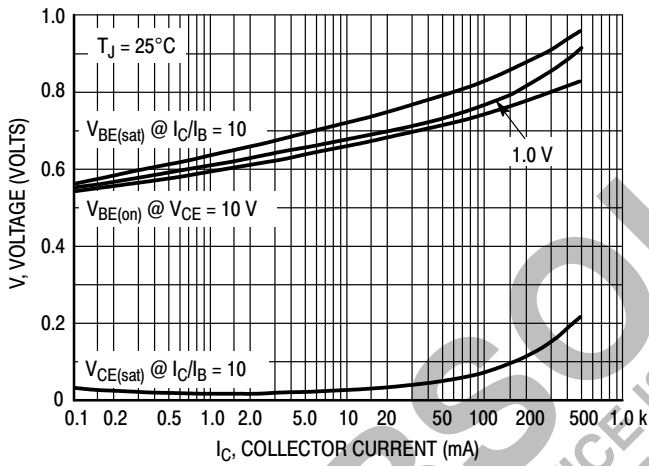


Figure 11. "On" Voltages

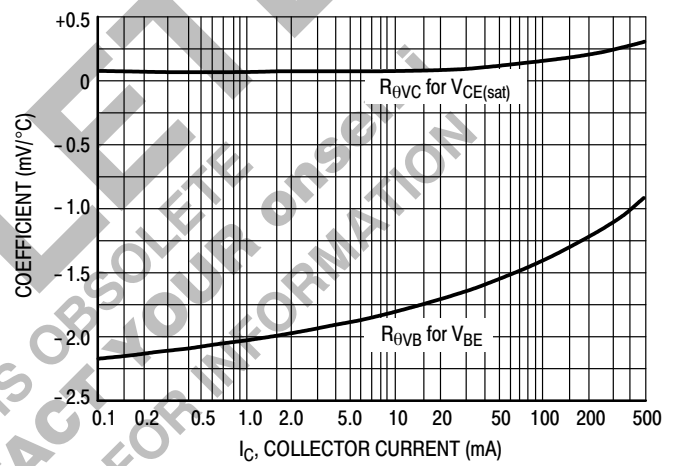


Figure 12. Temperature Coefficients

ORDERING INFORMATION

Device	Package	Shipping†
MPS2222G	TO-92 (Pb-Free)	5000 Units / Bulk
MPS2222RLRP	TO-92	2000 / Tape & Ammo Box
MPS2222RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MPS2222A	TO-92	5000 Units / Bulk
MPS2222AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPS2222ARLG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPS2222ARLRA	TO-92	2000 / Tape & Reel
MPS2222ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel

MPS2222, MPS2222A

ORDERING INFORMATION

Device	Package	Shipping†
MPS2222ARLRMG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPS2222ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box

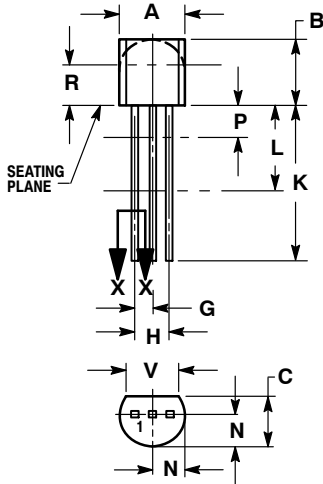
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

OBSOLETE
THIS DEVICE IS OBSOLETE
PLEASE CONTACT YOUR onsemi
REPRESENTATIVE FOR INFORMATION

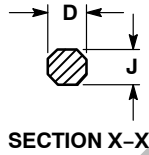
MPS2222, MPS2222A

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AM



STRAIGHT LEAD
BULK PACK

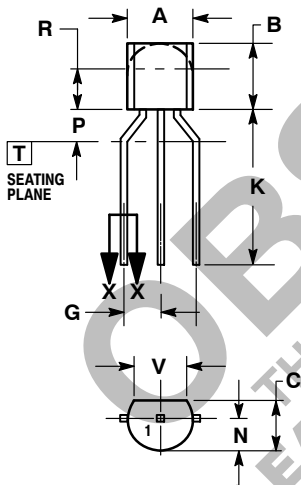


SECTION X-X

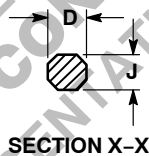
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X-X

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 1:

1. PIN 1. EMITTER
2. BASE
3. COLLECTOR

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